

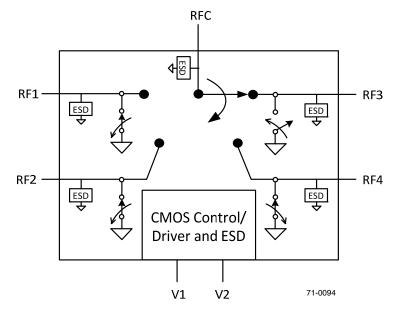
### **Product Description**

The PE423641 is a HaRP™ technology-enhanced reflective SP4T RF switch. It has received AEC-Q100 Grade 2 certification and meets the quality and performance standards that makes it suitable for use in harsh automotive environments. It is designed to cover a wide range of wireless applications from 50 MHz through 3 GHz such as cellular antenna band switching, automotive infotainment and traffic safety applications. No blocking capacitors are required if DC voltage is not present on the RF ports.

The PE423641 is manufactured on Peregrine's UltraCMOS® process, a patented variation of silicon-oninsulator (SOI) technology on a sapphire substrate, offering excellent RF performance.

Peregrine's HaRP™ technology enhancements deliver high linearity and excellent harmonics performance. It is an innovative feature of the UltraCMOS process, offering the performance of GaAS with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram



# **Product Specification**

# PE423641

### UltraCMOS® SP4T RF Switch 50-3000 MHz

#### **Features**

- AEC-Q100 Grade 2 certified
- Supports operating temperature up to +105°C
- HaRP<sup>TM</sup> technology enhancements provide excellent linearity
  - Low harmonics of 2fo = -83 dBc and  $3fo = -77 \, dBc @ +35 \, dBm$
  - IMD3 of –111 dBm @ WCDMA band 1
  - IIP3 of 68 dBm
- Low insertion loss
  - 0.50 dB @ 1000 MHz
  - 0.65 dB @ 2200 MHz
- High isolation
  - 32 dB @ 1000 MHz
  - 25 dB @ 2200 MHz
- High ESD performance
  - 2 kV HBM on all pins
  - 100V MM on all pins
  - 1 kV CDM on all pins
- Integrated decoder for 2-pin control
  - Accepts 1.8V and 2.75V levels

Figure 2. Package Type 16-lead 3 x 3 mm QFN





## Table 1. Electrical Specifications @ +25°C, $V_{DD}$ = 2.75V ( $Z_S$ = $Z_L$ = $50\Omega$ )

Parameter	Path	Condition	Min	Тур	Max	Unit
Operational frequency			50		3000	MHz
		50–1000 MHz		0.50	0.60	dB
Insertion loss	RFC-RFX	1000–2200 MHz		0.65	0.75	dB
(symmetric ports)	RFC-RFX	2200–2700 MHz		0.80	0.95	dB
		2700–3000 MHz		0.95	1.15	dB
		50–1000 MHz	30	32		dB
Isolation	RFC-RFX	1000–2200 MHz	23	25		dB
Isolation	111 0-111 X	2200–2700 MHz	21	23		dB
		2700–3000 MHz	20	22		dB
		50–1000 MHz		24		dB
Return loss (active ports)	RFC-RFX	1000–2200 MHz		19		dB
Thetain loss (active ports)	111 0-111 X	2200–2700 MHz		16		dB
		2700–3000 MHz		14		dB
	RFC-RFX	50–1000 MHz		23		dB
		1000–2200 MHz		16		dB
Return loss (common ports)		2200–2700 MHz		14		dB
		2700–3000 MHz		13		dB
2nd harmonic	RFX	+35 dBm output power, 850/900 MHz		-83	-80	dBc
Zila Haimonic	пх	+33 dBm output power, 1800/1900 MHz		-85	-78	dBc
Ord harmania	RFX	+35 dBm output power, 850/900 MHz		-77	-73.5	dBc
3rd harmonic		+33 dBm output power, 1800/1900 MHz		-78	-72.5	dBc
IMD3		RF Measured at 2.14 GHz at ANT port, input +20 dBm CW signal at 1.95 GHz and –15 dBm CW signal at 1.76 GHz		-111		dBm
Input IP2	RFC-RFX	50–3000 MHz		115		dBm
Input IP3	RFC-RFX	50–3000 MHz		68		dBm
Input 0.1 dB compression point <sup>1</sup>	RFC-RFX	50–3000 MHz		37		dBm
Switching time		50% CTRL to 90% or 10% RF		1	2	μs

Note 1: Input 0.1 dB compression point is a linearity figure of merit. Refer to  $Table\ 3$  for the operating RF input power (50 $\Omega$ ).



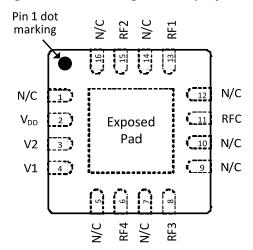
Table 1A. Electrical Specifications @ –40 to +105°C,  $V_{DD}$  = 2.75V ( $Z_S$  =  $Z_L$  =  $50\Omega$ )

Parameter	Path	Condition	Min	Тур	Max	Unit
Operational frequency			50		3000	MHz
		50–1000 MHz		0.50	0.75	dB
Insertion loss	RFC-RFX	1000–2200 MHz		0.65	0.90	dB
(symmetric ports)	HFC-HFX	2200–2700 MHz		0.80	1.10	dB
		2700–3000 MHz		0.95	1.30	dB
		50–1000 MHz	30	32		dB
Isolation	RFC-RFX	1000–2200 MHz	23	25		dB
ISOIdtion	NFU-NFX	2200–2700 MHz	21	23		dB
		2700–3000 MHz	20	22		dB
		50–1000 MHz		24		dB
Return loss (active ports)	RFC-RFX	1000–2200 MHz		19		dB
neturn loss (active ports)	RFC-RFX	2200–2700 MHz		16		dB
		2700–3000 MHz		14		dB
		50–1000 MHz		23		dB
	RFC-RFX	1000–2200 MHz		16		dB
Return loss (common ports)		2200–2700 MHz		14		dB
		2700–3000 MHz		13		dB
2nd harmonic	RFX	+35 dBm output power, 850/900 MHz		-83	-76	dBc
Ziiu iiaiiiioiiic	пх	+33 dBm output power, 1800/1900 MHz		-85	-74	dBc
Outhouse	DEV	+35 dBm output power, 850/900 MHz		-77	-69.5	dBc
3rd harmonic	RFX	+33 dBm output power, 1800/1900 MHz		-78	-68.5	dBc
IMD3		RF Measured at 2.14 GHz at ANT port, input +20 dBm CW signal at 1.95 GHz and -15 dBm CW signal at 1.76 GHz		-111		dBm
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Note 1: Input 0.1 dB compression point is a linearity figure of merit. Refer to  $Table\ 3$  for the operating RF input power (50 $\Omega$ ).



Figure 3. Pin Configuration (Top View)



**Table 2. Pin Descriptions** 

Pin #	Pin Name	Description
1, 5, 7, 9, 10, 12, 14, 16	N/C	No connect
2	$V_{DD}$	Supply voltage
3	V2	Digital control logic input 2
4	V1	Digital control logic input 1
6	RF4 <sup>1</sup>	RF port
8	RF3 <sup>1</sup>	RF port
11	RFC <sup>1</sup>	RF common
13	RF1 <sup>1</sup>	RF port
15	RF2 <sup>1</sup>	RF port
Pad	GND	Exposed pad: Ground for proper operation

Note 1: RF pins 6, 8, 13, and 15 must be at 0 VDC. The RF pins do not require DC blocking capacitors for proper operation if the 0 VDC requirement is met.

**Table 3. Operating Ranges** 

Parameter	Symbol	Min	Тур	Max	Unit
Supply voltage	$V_{DD}$	2.65	2.75	3.3	٧
Supply current (V <sub>DD</sub> = 2.75V, +25°C only)	I <sub>DD</sub>		13	50	μΑ
Digital input high (V1, V2)	$V_{IH}$	1.4		$V_{DD}$	٧
Digital input low (V1, V2)	V <sub>IL</sub>	0		0.4	V
RF input power, CW1	P <sub>MAX,CW</sub>			+35	dBm
Operating temperature range	T <sub>OP</sub>	-40	+25	+105	°C

Note 1: 100% duty cycle, all bands,  $50\Omega$ 

**Table 4. Absolute Maximum Ratings** 

Parameter/Condition	Symbol	Min	Max	Unit
Supply voltage	$V_{DD}$	-0.3	3.7	٧
Digital input voltage (V1, V2)	Vı	-0.3	3.7	٧
RF input power, max	P <sub>MAX,ABS</sub>		+37	dBm
Storage temperature range	T <sub>ST</sub>	-65	+150	°C
ESD voltage HBM <sup>1</sup> , all pins	V <sub>ESD</sub> ,HBM		2000	V
ESD voltage MM <sup>2</sup> , all pins	$V_{ESD,MM}$		100	V
ESD voltage CDM <sup>3</sup> , all pins	$V_{\text{ESD,CDM}}$		1000	٧

: 1. Human Body Model (MIL-STD-883 Method 3015)

2. Machine Model (JEDEC JESD22-A115)

3. Charged Device Model (JEDEC JESD22-C101)

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.



### **Electrostatic Discharge (ESD) Precautions**

When handling this UltraCMOS device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

### Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.

### **Moisture Sensitivity Level**

The Moisture Sensitivity Level rating for the PE423641 in the 16-lead 3x3 mm QFN package is MSL1.

**Table 5. Truth Table** 

Path	V2	V1
RFC-RF1	0	0
RFC-RF2	1	0
RFC-RF3	0	1
RFC-RF4	1	1

### **Switching Frequency**

The PE423641 has a maximum 25 kHz switching frequency.

Switching frequency describes the time duration between switching events. Switching time is the time duration between the point the control signal reaches 50% of the final value and the point the output signal reaches within 10% or 90% of its target value. Switching time is provided in *Table 1* and *Table 1A*.



## Typical Performance Data @ +25°C and V<sub>DD</sub> = 2.75V, unless otherwise specified

Figure 4. Insertion Loss vs Temp (RFC-RFX)

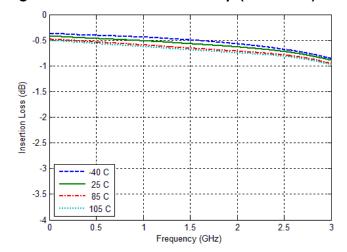


Figure 6. Return Loss vs Temp (Active Port)

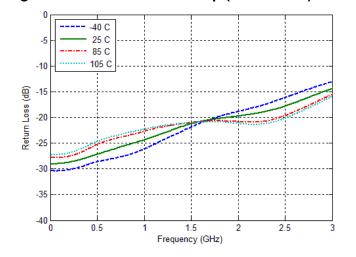
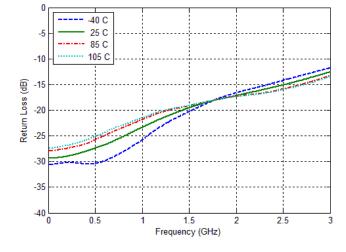


Figure 8. Return Loss vs Temp (Common Port)



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Figure 5. Insertion Loss vs V<sub>DD</sub> (RFC–RFX)

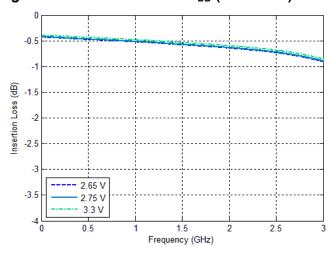


Figure 7. Return Loss vs V<sub>DD</sub> (Active Port)

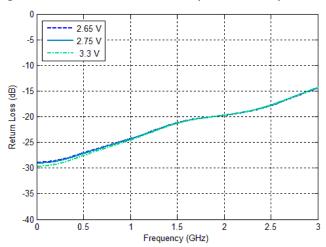
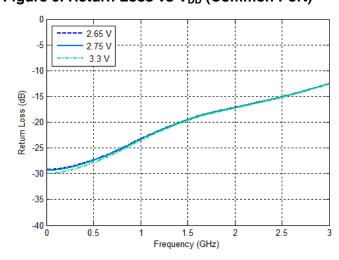


Figure 9. Return Loss vs V<sub>DD</sub> (Common Port)



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## Typical Performance Data @ +25°C and V<sub>DD</sub> = 2.75V, unless otherwise specified

Figure 10. Isolation vs Temp (RFC-RFX)

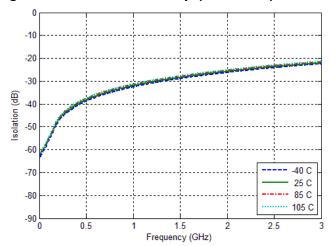
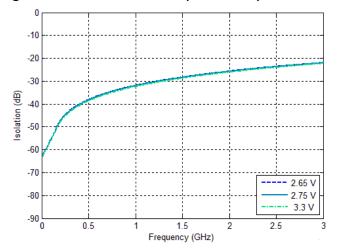


Figure 11. Isolation vs  $V_{DD}$  (RFC-RFX)



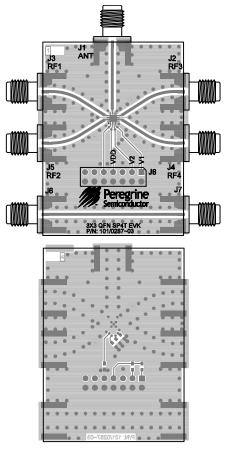


### **Evaluation Kit**

The SP4T switch evaluation board was designed to ease customer evaluation of Peregrine's PE423641. The RF common port is connected through a  $50\Omega$  transmission line via the top SMA connector, J1. RF1, RF2, RF3 and RF4 are connected through  $50\Omega$  transmission lines via SMA connectors J3, J5, J2 and J4, respectively. A through  $50\Omega$  transmission is available via SMA connectors J6 and J7. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a four metal layer FR4 material with a total thickness of 62 mils. The middle layers provide ground for the transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 32 mils, trace gaps of 25 mils, and metal thickness of 2.1 mils.

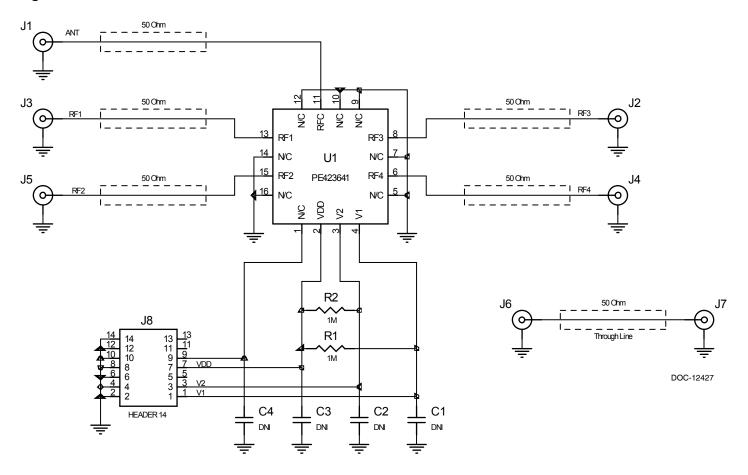
Figure 12. Evaluation Board Layouts



PRT-50900



### Figure 13. Evaluation Board Schematic



Caution: Contains parts and assemblies susceptible to damage by electrostatic discharge (ESD).



Figure 14. Package Drawing 16-lead 3x3 mm QFN

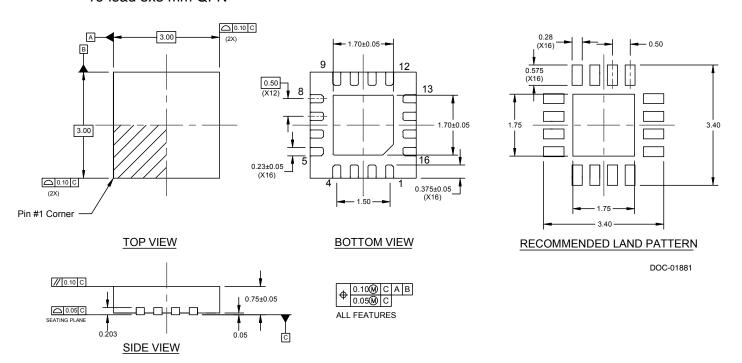
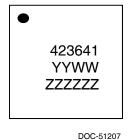


Figure 15. Top Marking Specification



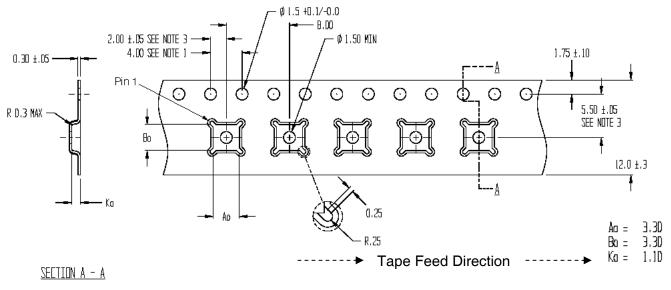
● = Pin 1 designator

YYWW = Date code, last two digits of the year and work week

ZZZZZZ = Last six characters of the assembly lot code

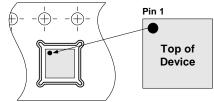


### Figure 16. Tape and Reel Specifications



#### NOTES:

- 1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.2
- 2. CAMBER IN COMPLIANCE WITH EIA 481
- 3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE



Device Orientation in Tape

### **Table 6. Ordering Information**

Order Code	Description	Package	Shipping Method	
PE423641MLAA-Z	PE423641 SP4T RF switch	Green 16-lead 3 x 3 mm QFN	3000 units / T&R	
EK423641-01	PE423641 Evaluation kit	Evaluation kit	1 / Box	

#### **Sales Contact and Information**

For sales and contact information please visit www.psemi.com.

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